



FEATURES

- Common cathode structure
- Low power loss, high efficiency
- High Operating Junction Temperature
- Guard ring for overvoltage protection, High reliability
- RoHS product

APPLICATIONS

- High frequency switch Power supply
- Free wheeling diodes, Polarity protection applications

主要参数 MAIN CHARACTERISTICS

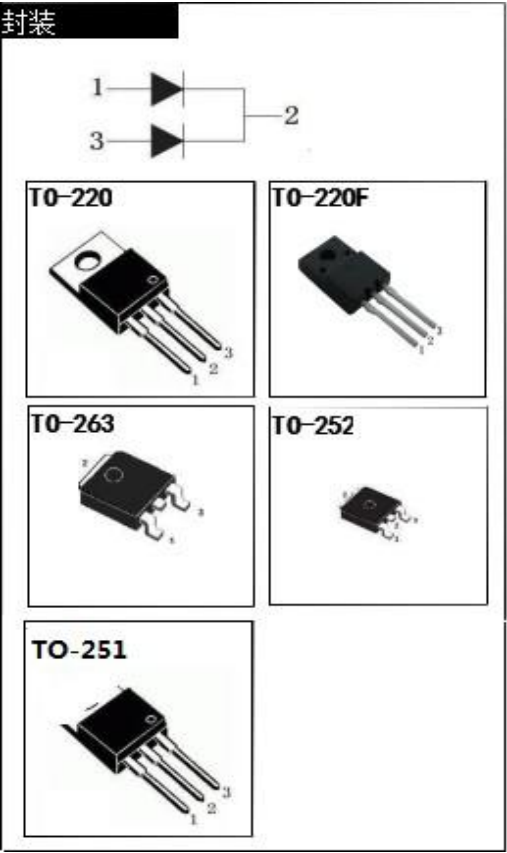
I _{F(AV)}	10 (2×5) A
V _{F(max)}	0.75V (@T _j =125℃)
T _j	175 ℃
V _{RRM}	200 V

产品特性

- 共阴结构
- 低功耗，高效率
- 良好的高温特性
- 有过压保护环，高可靠性
- 环保（RoHS）产品

用途

- 高频开关电源
- 低压续流电路和保护电路



产品型号信息 PRODUCT MESSAGE

型 号 Model	印 记 Marking	封 装 Package
MBR10200C	MBR10200C	TO-220
MBRF10200	MBRF10200	TO-220F
MBR10200S	MBR10200S	TO-263
MBR10200R	MBR10200R	TO-252
MBR10200V	MBR10200V	TO-251



绝对最大额定值 **ABSOLUTE RATINGS** ($T_c=25^{\circ}\text{C}$)

项 目 Parameter			符 号 Symbol	数 值 Value	单 位 Unit
最大反向重复峰值电压 Repetitive peak reverse voltage			V_{RRM}	200	V
最大直流阻断电压 Maximum DC blocking voltage			V_{DC}	200	V
正向平均整流电流 Average forward current	$T_c=150^{\circ}\text{C}$ (TO-220/263/252)	整个器件 per device	$I_{F(AV)}$	10	A
	$T_c=125^{\circ}\text{C}$ (TO-220F)	单 侧 per diode		5	
正向峰值浪涌电流 Surge non repetitive forward current (额定负载 8.3ms 半正弦波—按 JEDEC 方法) 8.3 ms single half-sine-wave (JEDEC Method)			I_{FSM}	125	A
最高结温 Maximum junction temperature			T_j	175	$^{\circ}\text{C}$
储存温度 Storage temperature range			T_{STG}	-40~+175	$^{\circ}\text{C}$

电特性 **ELECTRICAL CHARACTERISTICS**

项 目 Parameter	测试条件 Tests conditions		最小值 Value(min)	典型值 Value(typ)	最大值 Value(max)	单位 Unit
I_R	$T_j = 25^{\circ}\text{C}$	$V_R = V_{RRM}$			10	μA
	$T_j = 125^{\circ}\text{C}$				5	mA
V_F	$T_j = 25^{\circ}\text{C}$	$I_F = 5\text{A}$		0.85	0.93	V
	$T_j = 125^{\circ}\text{C}$			0.71	0.75	V
	$T_j = 25^{\circ}\text{C}$	$I_F = 10\text{A}$		0.94	0.98	V
	$T_j = 125^{\circ}\text{C}$			0.81	0.86	V

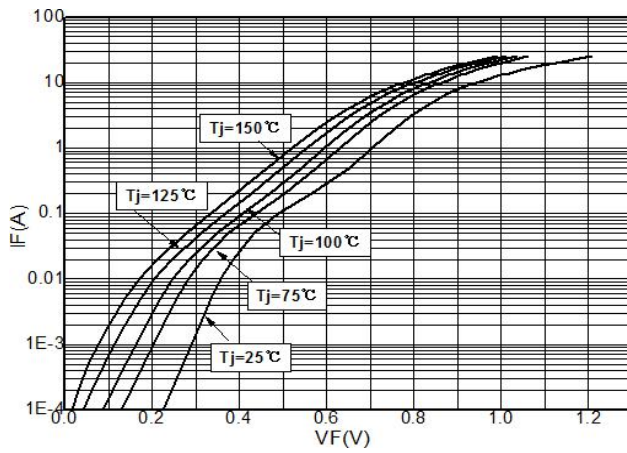
热特性 **THERMAL CHARACTERISTICS**

项 目 Parameter		符 号 Symbol	最小值 Value(min)	最大值 Value(max)	单 位 Unit
结到管壳的热阻 Thermal resistance from junction to case	TO-220	$R_{th(j-c)}$		1.9	$^{\circ}\text{C/W}$
	TO-220F			3.5	
	TO-263			1.9	
	TO-252			3.0	

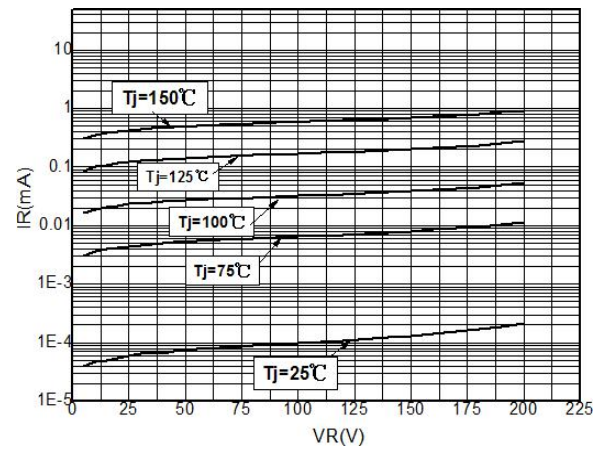


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

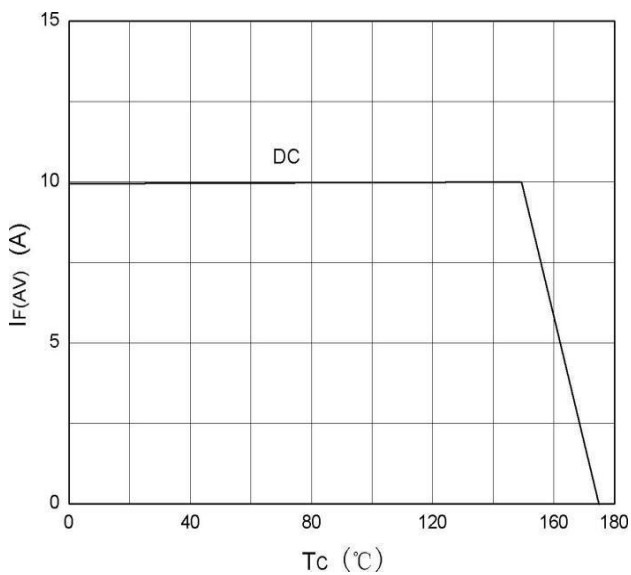
I_F vs V_F



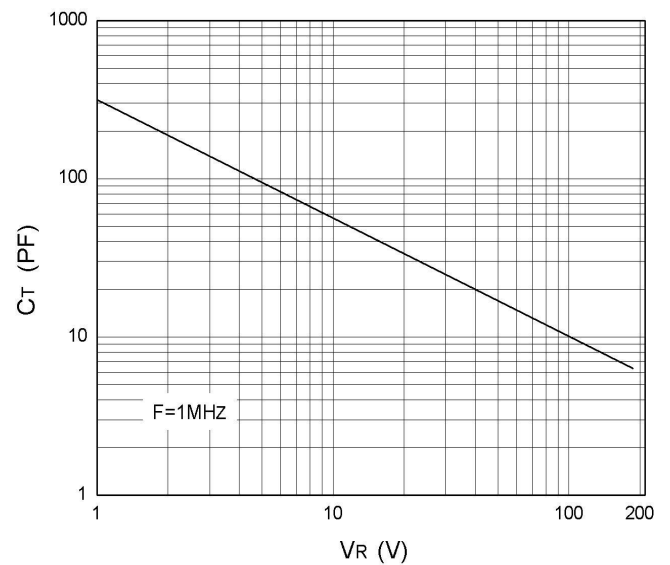
I_R vs V_R



$I_F(AV)$ vs T_C



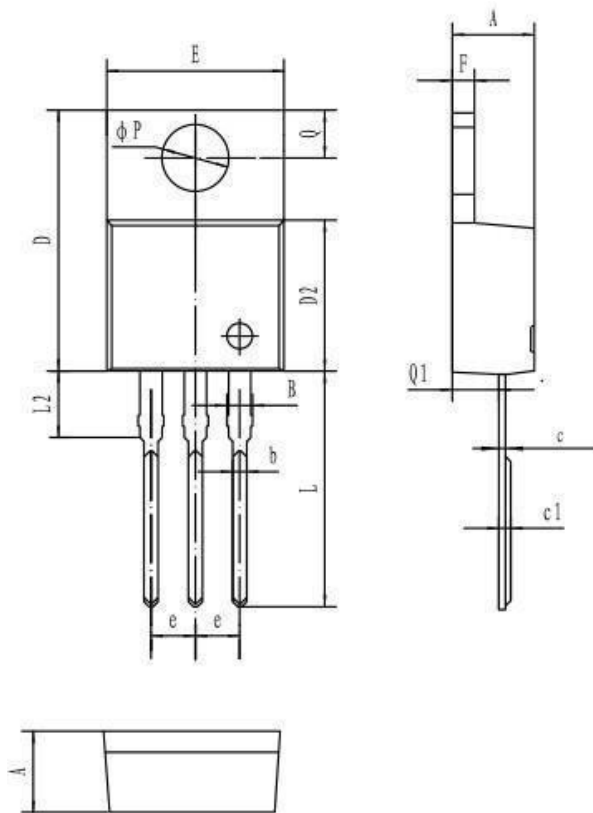
C_T vs V_R





外形尺寸 PACKAGE MECHANICAL DATA
TO-220

单位 Unit : mm



符号 symbol	MIN	MAX
A	4.40	4.80
B	1.10	1.40
b	0.70	0.95
c	0.28	0.48
c1	0.32	0.52
D	14.45	16.00
D2	8.20	9.20
E	9.60	10.40
e	2.39	2.69
F	1.20	1.35
L	13.05	14.05
L2	3.70	3.90
Q	2.40	3.00
Q1	2.20	2.90
P	3.50	4.00

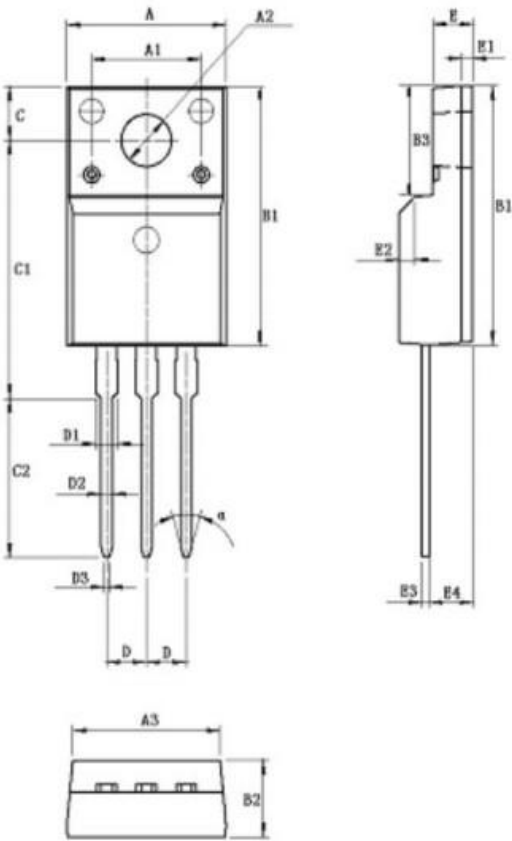


外形尺寸 **PACKAGE MECHANICAL DATA**
TO-220F

单位 **Unit** : mm

Package Dimension

TO-220F



单位: mm

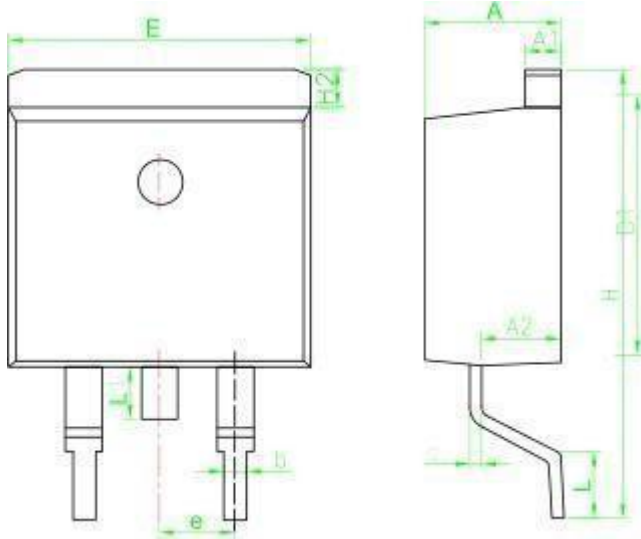
Symbol	Min	Max	Symbol	Min	Max
A	9.96	10.36	D	2.54	
A1	7.00		D1	1.15	1.35
A2	3.08	3.28	D2	0.70	0.90
A3	9.25	9.65	D3	0.28	0.48
B1	15.70	16.10	E	2.34	2.74
B2	4.50	4.90	E1	0.70	
B3	6.20	6.80	E2	1.0×45°	
C	3.20	3.40	E3	0.36	0.65
C1	15.20	16.00	E4	2.55	2.95
C2	9.75	10.15	a(度)	30°	



MBR10200 肖特基二极管 SCHOTTKY DIODE

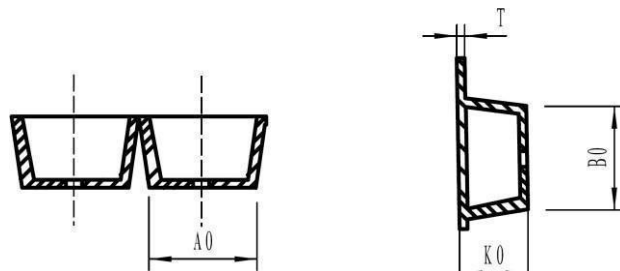
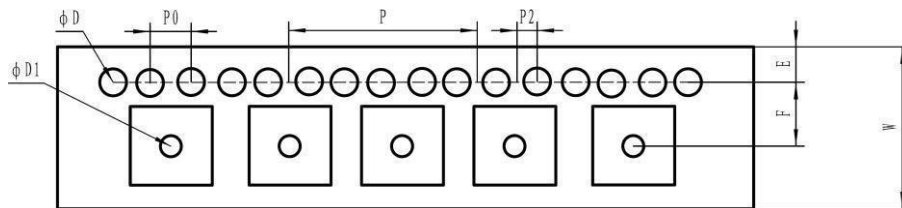
外形尺寸 PACKAGE MECHANICAL DATA TO-263

单位 Unit : mm



SYMBOL	MM	
	MIN	MAX
A	4.30	4.80
A1	1.12	1.42
A2	2.54	2.84
b	0.67	1.00
c	0.29	0.52
D1	8.40	9.00
E	9.80	10.46
e	2.54BSC	
H	14.00	16.00
H2	1.12	1.45
L	1.50	3.10
L1	1.45	1.70

编带 REEL

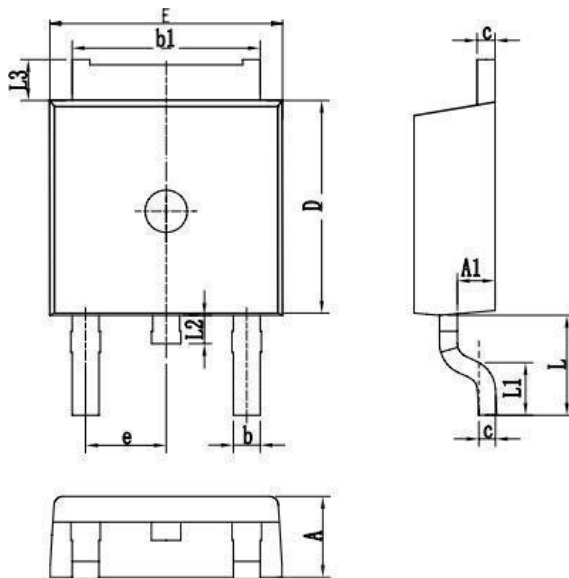


产品尺寸规格 (UNIT: mm)				
规格	W	A0	E	F
尺寸	24 ± 0.3	10.9 ± 0.2	1.75 ± 0.2	11.5 ± 0.2
规格	D1	P0	P2	P
尺寸	1.5 ± 0.2/-0.1	4 ± 0.2	2 ± 0.2	16 ± 0.2
规格	K0	B0		
尺寸	4.9 ± 0.2	16.0 ± 0.2		



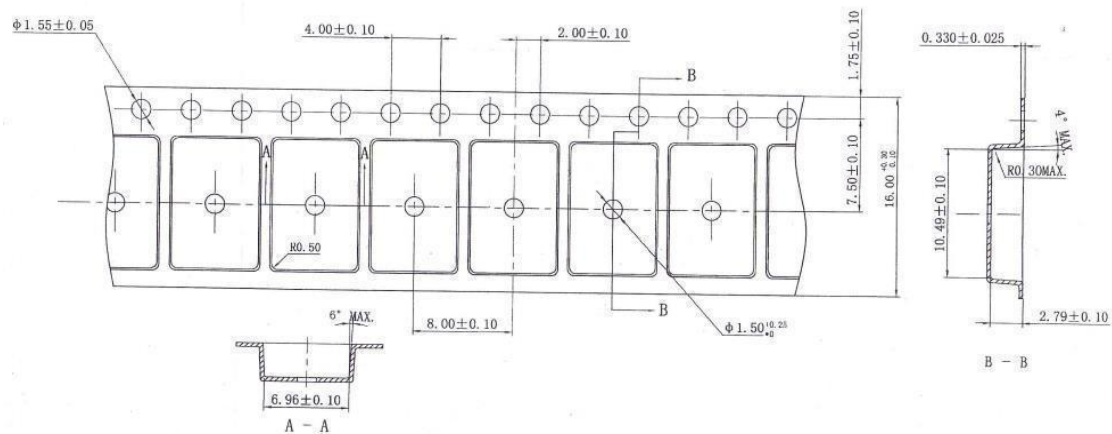
外形尺寸 PACKAGE MECHANICAL DATA
TO-252

单位 Unit : mm



SYMBOL	mm	
	MIN	MAX
A	2.10	2.50
A1	0.80	1.20
b	0.66	0.96
b1	5.10	5.50
c	0.40	0.62
D	5.85	6.45
E	6.30	6.90
e	2.286BSC	
L	2.40	3.00
L1	0.85	1.45
L2	0.60	1.10
L3	0.67	1.07

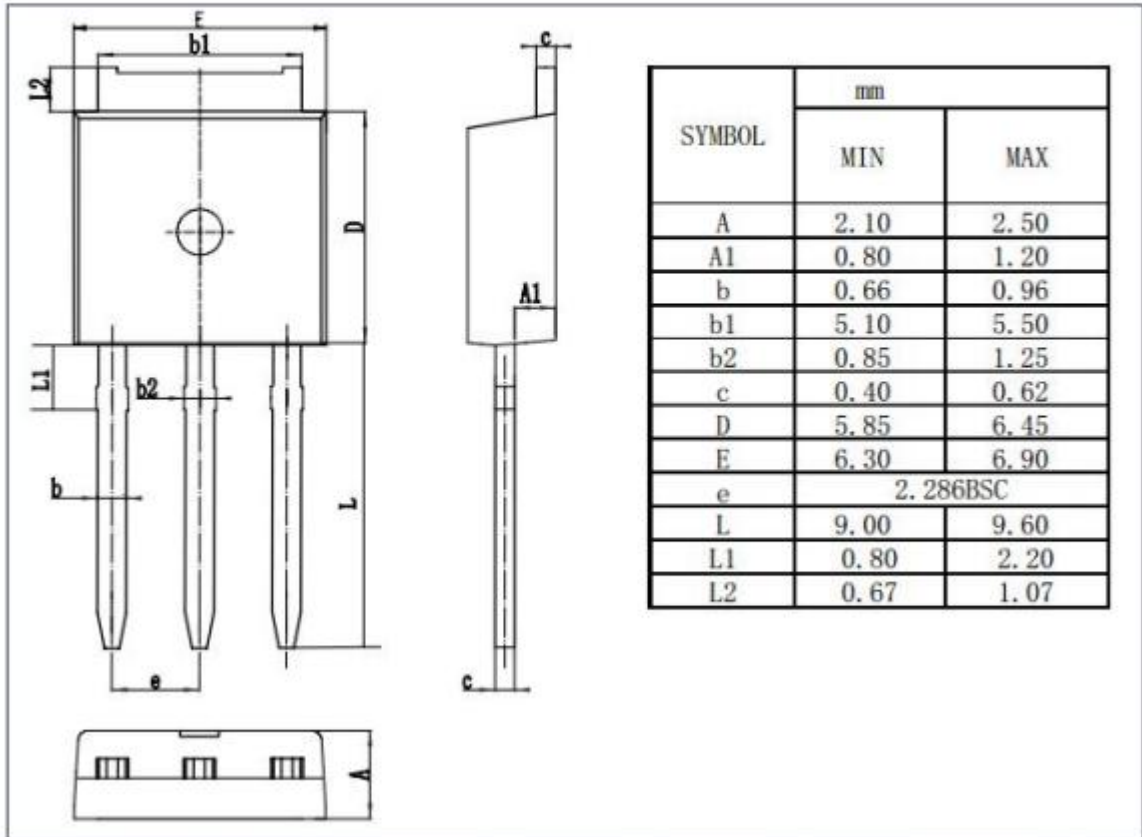
编带 REEL





外形尺寸 PACKAGE MECHANICAL DATA
TO-251

单位 Unit : mm





注意事项

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2. 购买时请认清公司商标，如有疑问请与公司本部联系。
3. 在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
4. 本说明书如有版本变更不另外告知

NOTE

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2. We strongly recommend customers check carefully on the trademark when buying our product, if there is any question, please don't be hesitate to contact us.
3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
4. Shenzhen Huatianwei Electronics co., Ltd reserves the right to make changes in this specification sheet and is subject to change without prior notice.

联系方式

深圳市华天微电子有限公司

公司地址：广东省深圳市龙华清湖硅谷动力清湖园A14栋3楼

电话：86-755-82047720

网址：www.htwdz.com.cn

邮箱：grf@htwdz.com.cn

CONTACT

SHENZHEN HUATIANWEI ELECTRONICS CO., LTD.

ADD: Floor 3,Building A14,Qinghu Power park, Qinghu Silicon Valley,Longhua, Shenzhen,China

TEL: 86-755-82047720

Web Site: www.htwdz.com.cn

邮箱：grf@htwdz.com.cn